

Description

The μPD27C1024A is a 1,048,576-bit ultraviolet erasable and electrically programmable ROM fabricated with an advanced CMOS process for substantial power savings. The device is organized as 65,536 words by 16 bits and operates from a single +5-volt power supply. All inputs and outputs are TTL-compatible.

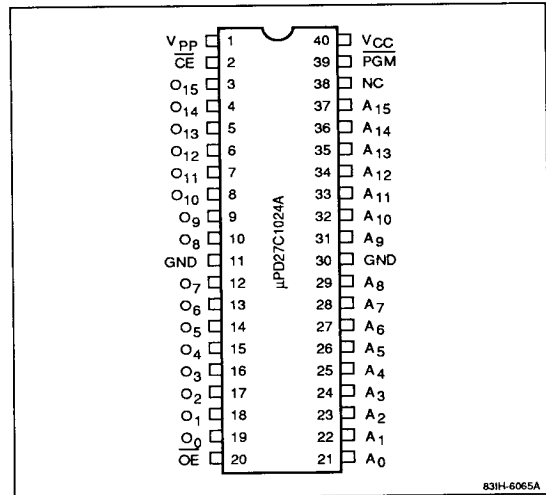
The μPD27C1024A is available in a 40-pin ceramic DIP with quartz window.

Features

- 65,536 x 16-bit organization
- Ultraviolet erasable and electrically programmable
- High-speed word and page programming
- Low power dissipation
 - 50 mA max (active)
 - 100 μA max (standby)
- TTL-compatible inputs and outputs
- Three-state outputs
- Single +5-volt power supply
- Advanced CMOS technology
- 40-pin cerdip packaging with quartz window

Pin Configuration

40-Pin Cerdip



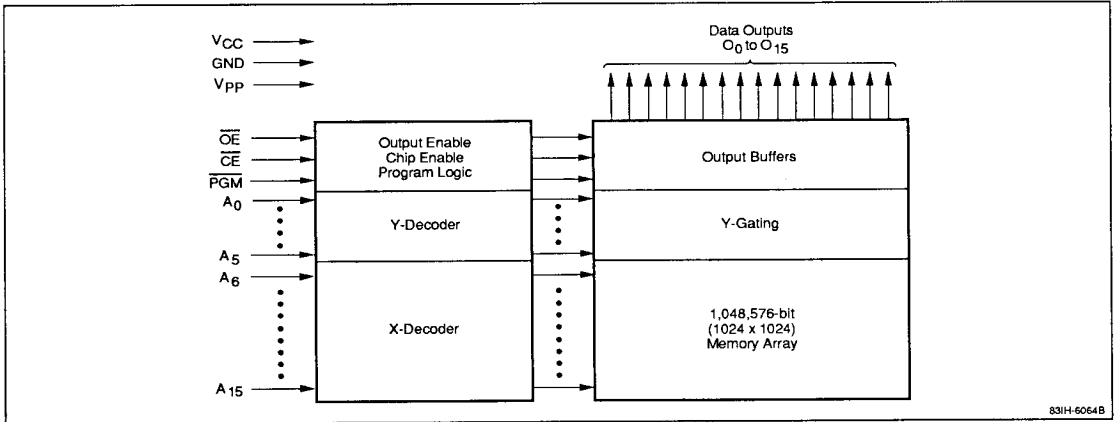
Ordering Information

Part Number	Access Time (max)	Package
μPD27C1024AD-12	120 ns	40-pin cerdip with quartz window
D-15	150 ns	
D-20	200 ns	

Pin Identification

Symbol	Function
A ₀ - A ₁₅	Address inputs
O ₀ - O ₁₅	Data outputs
\overline{CE}	Chip enable
\overline{OE}	Output enable
PGM	Program
GND	Ground
V _{CC}	+5-volt power supply
V _{PP}	Program voltage
NC	No connection

Block Diagram



Absolute Maximum Ratings

Operating temperature, T_{OPR}	-10 to +80°C
Storage temperature, T_{STG}	-65 to +125°C
Output voltage, V_{OUT}	-0.6 to +7.0 V
Input voltage, V_{IN}	-0.6 to $V_{CC} + 0.3$ V
Input voltage, A_9	-0.6 to +13.5 V
Supply voltage, V_{CC}	-0.6 to +7.0 V
Supply voltage, V_{PP}	-0.6 to +13.5 V

Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The device should be operated within the limits specified under DC and AC Characteristics.

Capacitance

$T_A = 25^\circ\text{C}$; $f = 1$ MHz; V_{IN} and $V_{OUT} = 0$ V

Parameter	Symbol	Min	Typ	Max	Unit
Input capacitance	C_{IN}			14	pF
Output capacitance	C_{OUT}			16	pF

Truth Table

Function	\overline{CE}	\overline{OE}	\overline{PGM}	V_{PP}	V_{CC}	Outputs
Read	V_{IL}	V_{IL}	V_{IH}	5.0 V	5.0 V	D_{OUT}
Output disable	V_{IL}	V_{IH}	X	5.0 V	5.0 V	High-Z
Standby	V_{IH}	X	X	5.0 V	5.0 V	High-Z
Page data latch	V_{IH}	V_{IL}	V_{IH}	12.5 V	6.5 V	D_{IN}
Page program	V_{IH}	V_{IH}	V_{IL}	12.5 V	6.5 V	High-Z
Word program	V_{IL}	V_{IH}	V_{IL}	12.5 V	6.5 V	D_{IN}
Program verify	V_{IL}	V_{IL}	V_{IH}	12.5 V	6.5 V	D_{OUT}
Program inhibit	X	V_{IL}	V_{IL}	12.5 V	6.5 V	High-Z
	X	V_{IH}	V_{IH}			

Notes:

- (1) X = V_{IL} or V_{IH} .
- (2) In read operation, \overline{PGM} must be set to V_{IH} at all times, or for at least 2 μs before \overline{OE} or \overline{CE} returns to V_{IH} .

Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Read Operation or Standby					
Supply voltage	V _{CC}	4.5	5.0	5.5	V
	V _{PP}	V _{CC} - 0.6	V _{CC}	V _{CC} + 0.6	V
Input voltage, high	V _{IH}	2.0		V _{CC} + 0.3	V
Input voltage, low	V _{IL}	-0.3		0.8	V
Operating temperature	T _A	0		70	°C
Programming Operation					
Supply voltage	V _{CC}	6.25	6.5	6.75	V
	V _{PP}	12.2	12.5	12.8	V
Input voltage, high	V _{IH}	2.0		V _{CC} + 0.3	V
Input voltage, low	V _{IL}	-0.3		0.8	V
Operating temperature	T _A	20	25	30	°C

DC Characteristics

T_A = 0 to +70°C; V_{CC} = +5.0 V ± 10%; V_{PP} = V_{CC} ± 0.6 V

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Read Operation						
Output voltage, high	V _{OH1}	2.4			V	I _{OH} = -400 μA
	V _{OH2}	V _{CC} - 0.7			V	I _{OH} = -100 μA
Output voltage, low	V _{OL}		0.45		V	I _{OL} = 2.1 mA
Output leakage current	I _{LO}	-10	10		μA	V _{OUT} = 0 to V _{CC} ; $\overline{OE} = V_{IH}$
Input leakage current	I _{LI}	-10	10		μA	V _{IN} = 0 to V _{CC}
V _{PP} current	I _{PP}		1	100	μA	V _{PP} = V _{CC}
V _{CC} current (active)	I _{CCA1}			15	mA	$\overline{CE} = V_{IL}$; V _{IN} = V _{IH}
	I _{CCA2}			50	mA	f = 8.4 MHz; I _{OUT} = 0 mA
V _{CC} current (standby)	I _{CCS1}			1	mA	$\overline{CE} = V_{IH}$ min
	I _{CCS2}		1	100	μA	$\overline{CE} \geq V_{CC} - 0.2$ V; V _{IN} = 0 to V _{CC}

DC Characteristics (cont)

T_A = 25 ± 5°C; V_{CC} = +6.5 V ± 0.25; V_{PP} = +12.5 V ± 0.3

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Programming Operation						
Output voltage, high	V _{OH}	2.4			V	I _{OH} = -400 μA
Output voltage, low	V _{OL}		0.45		V	I _{OL} = 2.1 mA
Input leakage current	I _{LI}	-10		10	μA	V _{IN} = 0 to V _{CC}
V _{PP} current	I _{PP}			50	mA	$\overline{CE} = \overline{PGM} = V_{IL}$
V _{CC} current	I _{CC}			30	mA	

AC Characteristics

$T_A = 0 \text{ to } +70^\circ\text{C}; V_{CC} = +5.0 \text{ V} \pm 10\%; V_{PP} = V_{CC} \pm 0.6 \text{ V}$

Parameter	Symbol	μPD27C1024A-12		μPD27C1024A-15		μPD27C1024A-20		Unit	Test Conditions
		Min	Max	Min	Max	Min	Max		
Read Operation									
Address to output delay	t_{ACC}		120		150		200	ns	$\overline{CE} = \overline{OE} = V_{IL}$
\overline{CE} to output delay	t_{CE}		120		150		200	ns	$\overline{OE} = V_{IL}$
\overline{OE} to output delay	t_{OE}		60		70		70	ns	$\overline{CE} = V_{IL}$
\overline{OE} high to output float	t_{DF}	0	50	0	55	0	55	ns	$\overline{CE} = V_{IL}$
Address to output hold	t_{OH}	0		0		0		ns	$\overline{CE} = \overline{OE} = V_{IL}$

AC Characteristics (cont)

$T_A = 25 \pm 5^\circ\text{C}; V_{CC} = +6.5 \text{ V} \pm 0.25; V_{PP} = +12.5 \text{ V} \pm 0.3$

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Page Programming Operation						
Address setup time	t_{AS}	2			μs	
\overline{CE} setup time	t_{CES}	2			μs	
Data setup time	t_{DS}	2			μs	
Address hold time	t_{AH}	2			μs	
	t_{AHL}	2			μs	
	t_{AHV}	0			μs	
Data hold time	t_{DH}	2			μs	
\overline{OE} to output float time	t_{DF}	0		130	ns	
V_{PP} setup time	t_{VPS}	2			μs	
V_{CC} setup time	t_{VCS}	2			μs	
Program pulse width	t_{PW}	0.095	0.1	0.105	ms	
\overline{OE} setup time	t_{OES}	2			μs	
\overline{OE} to output delay	t_{OE}			150	ns	
\overline{OE} pulse width during data latch	t_{LW}	1			μs	
PGM setup time	t_{PGMS}	2			μs	
\overline{CE} hold time	t_{CEH}	2			μs	
OE hold time	t_{OEH}	2			μs	

AC Characteristics (cont)

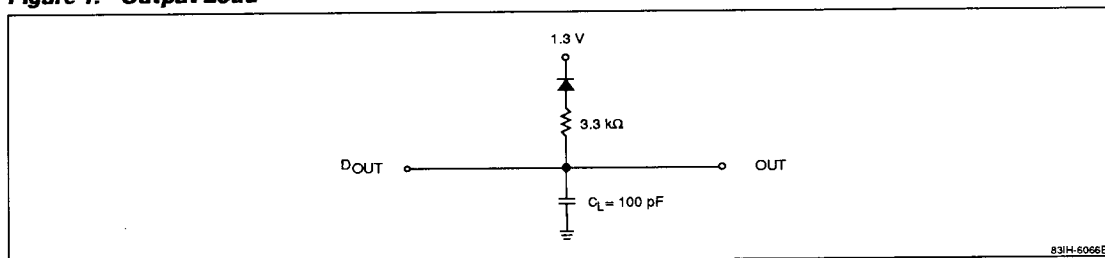
$T_A = 25 \pm 5^\circ\text{C}$; $V_{CC} = +6.5 \text{ V} \pm 0.25$; $V_{PP} = +12.5 \text{ V} \pm 0.3$

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Word Programming Operation						
Address setup time	t_{AS}	2			μs	
OE setup time	t_{OES}	2			μs	
Data setup time	t_{DS}	2			μs	
Address hold time	t_{AH}	2			μs	
Data hold time	t_{DH}	2			μs	
OE to output float time	t_{DF}	0		130	ns	
V_{PP} setup time	t_{VPS}	2			μs	
V_{CC} setup time	t_{VCS}	2			μs	
Program pulse width	t_{PW}	0.095	0.1	0.105	ms	
CE setup time	t_{CES}	2			μs	
OE to output delay	t_{OE}			150	ns	

Notes:

- (1) Input pulse levels = 0.45 to 2.4 V; input and output timing reference levels = 0.8 and 2.0 V; input rise and fall times ≤ 20 ns. See figure 1 for output load.

Figure 1. Output Load



8314-6068B

PROGRAMMING

Before programming the μPD27C1024A, erase all data; this sets all data bits high. The μPD27C1024A is originally shipped in this condition. To begin programming, first raise V_{CC} to $+6.5\text{ V} \pm 0.25$, and then raise V_{PP} to $12.5\text{ V} \pm 0.3$. At this point, data to be programmed can be directly input in 16-bit format through the data bus. Programming causes relevant bits to go low.

Word Programming

For word programming, \overline{CE} should be set low and \overline{OE} high to start programming at the initial address. A 0.1-ms pulse is applied to \overline{PGM} , as shown in the word programming portion of the timing waveforms, and \overline{OE} goes low to verify the 16 bits prior to making a program/no program decision. If the word is not programmed, another 0.1-ms pulse is applied to \overline{PGM} , up to a maximum of 10 times, before the next address is input. If the bits are not programmed in 10 tries, reject the device as a program failure.

After all addresses are programmed, lower both V_{CC} and V_{PP} to $+5.0\text{ V} \pm 10\%$ and verify all data again.

Page Programming

To begin page programming, \overline{CE} and \overline{PGM} should be set high and \overline{OE} pulsed low twice to latch the addressed two-word, one-page data. \overline{CE} and \overline{OE} subsequently go high and a 0.1-ms program pulse is applied to \overline{PGM} , as shown in the page programming portion of the timing waveforms. Immediately thereafter, \overline{CE} and \overline{OE} go low to verify the data prior to a program/no program decision being made. If the two words of page data are not programmed, another 0.1-ms pulse is applied to \overline{PGM} , up to a maximum of 10 times. If the page is not programmed in 10 tries, reject the device as a program failure.

Program Inhibit

The program inhibit option can be used in either word or page operation to program one of multiple μPD27C1024A devices whose \overline{CE} pins are independent and \overline{OE} , V_{PP} , and O_0 through O_{15} pins are connected in parallel. For word programming, \overline{OE} must be high and \overline{CE} of the device to be programmed low. For page programming, both \overline{OE} and \overline{CE} must be high. Applying a low-level TTL pulse to \overline{PGM} of the device to be programmed and a high-level TTL pulse to the \overline{PGM} pins of the other devices enables the one device to be programmed while the others are inhibited.

Program Verification

To verify that the device is correctly programmed, execute a normal read cycle with a high logic level applied to the \overline{PGM} pin and a low logic level applied to the \overline{CE} and \overline{OE} pins of the device to be verified. A high should be applied to the \overline{CE} or \overline{OE} pin of all other devices.

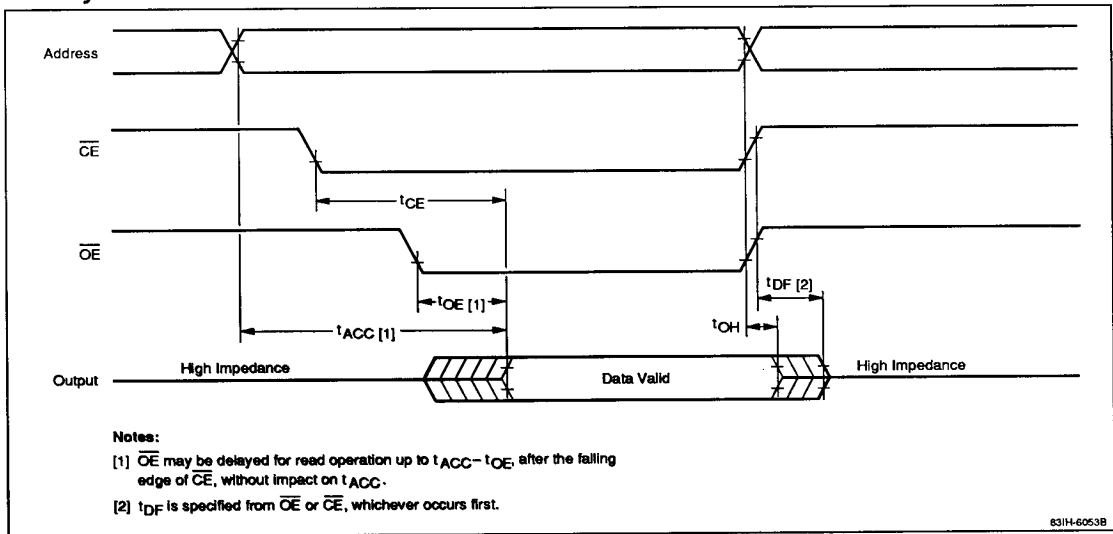
Erase

Erase data on the μPD27C1024A by exposing it to light with a wavelength shorter than 400 nm. Since exposure to direct sunlight or room-level fluorescent light could also erase the data, mask the window to prevent unintentional erasure by ultraviolet rays. Opaque labels are supplied with every device.

Data is typically erased by ultraviolet rays with a wavelength of 254 nm. A minimum integrated dose of 15 W-sec/cm² (ultraviolet lighting intensity multiplied by exposure time) is required to completely erase written data. Using an ultraviolet lamp rated at 12,000 μW/cm², it takes approximately 20 minutes to complete erasure. Place the μPD27C1024A within 2.5 cm of the lamp tubes and remove any filter on the lamp.

Timing Waveforms

Read Cycle



Timing Waveforms (cont)

Page Programming Cycle

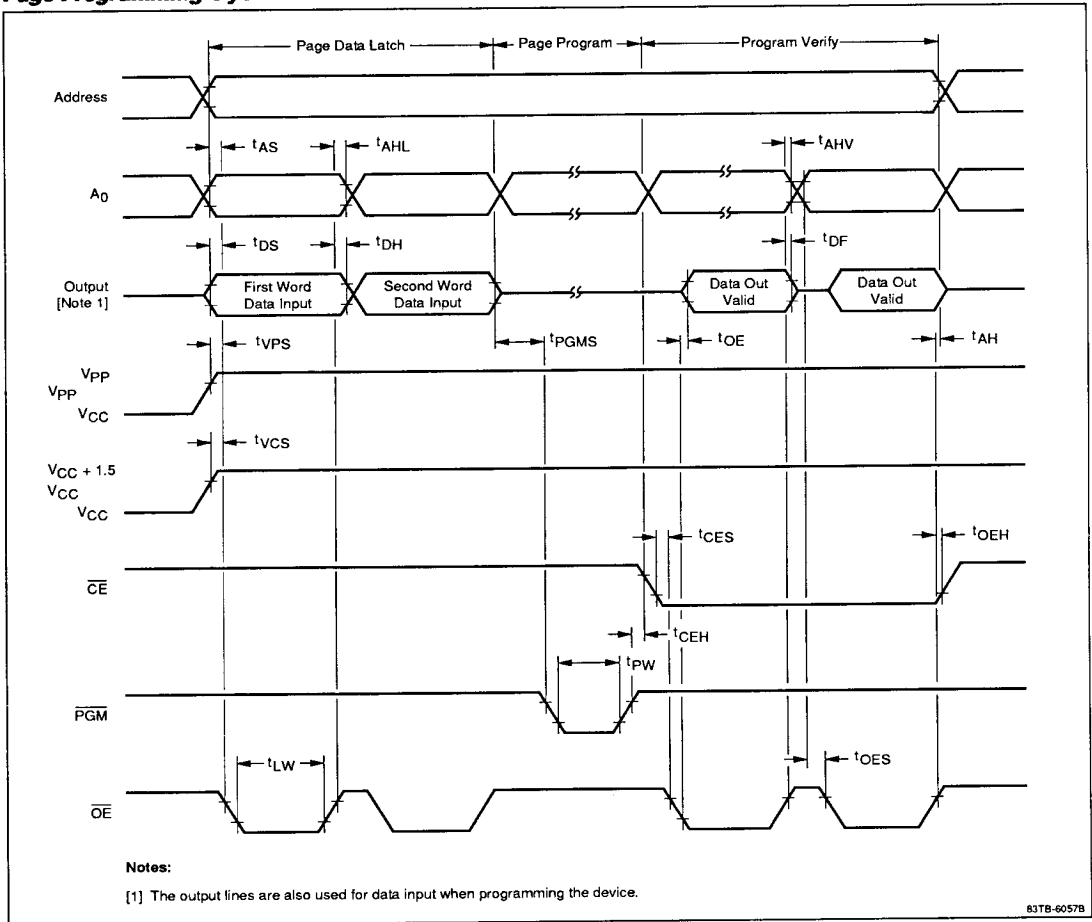
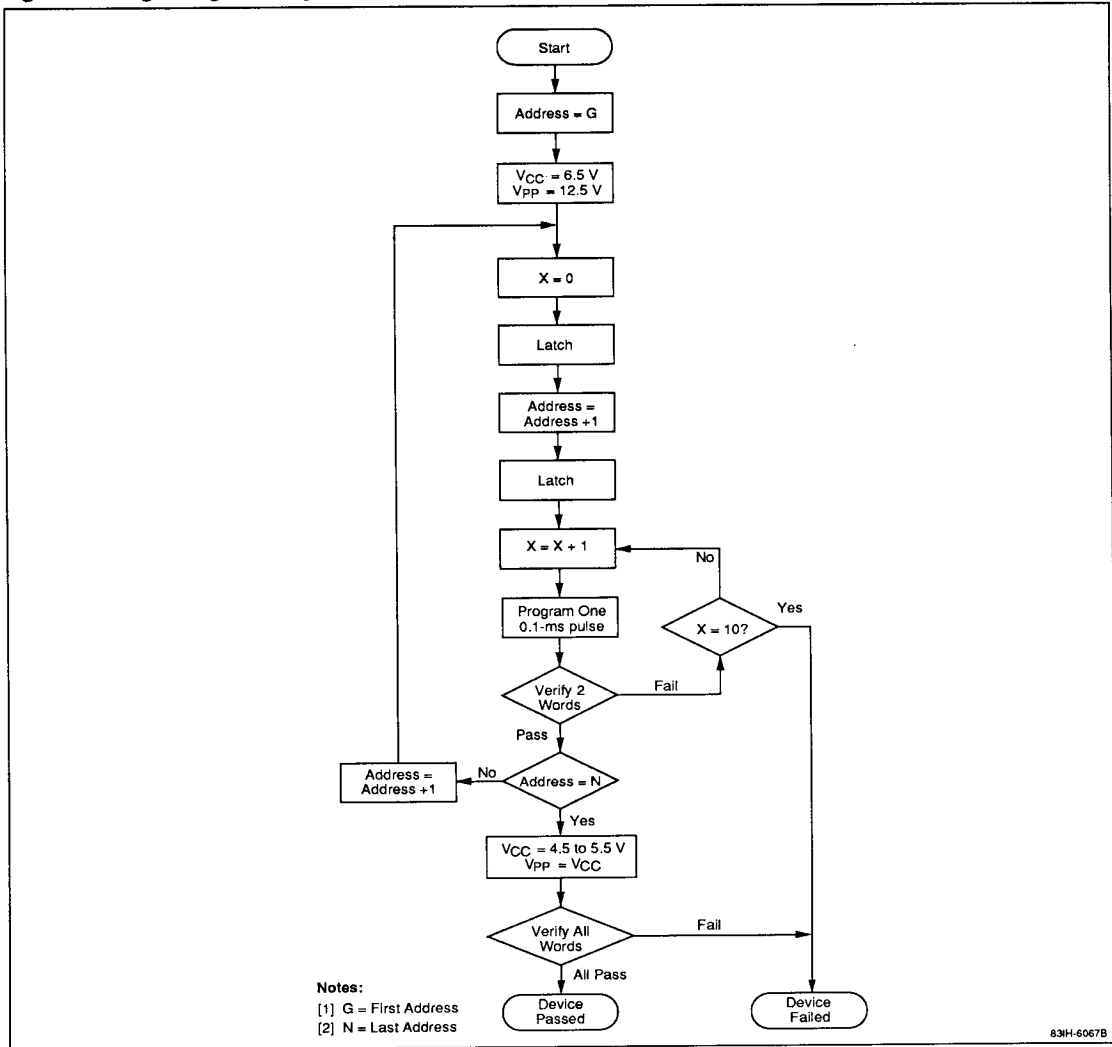


Figure 2. Page Programming Flowchart



Timing Waveforms (cont)

Word Programming Cycle

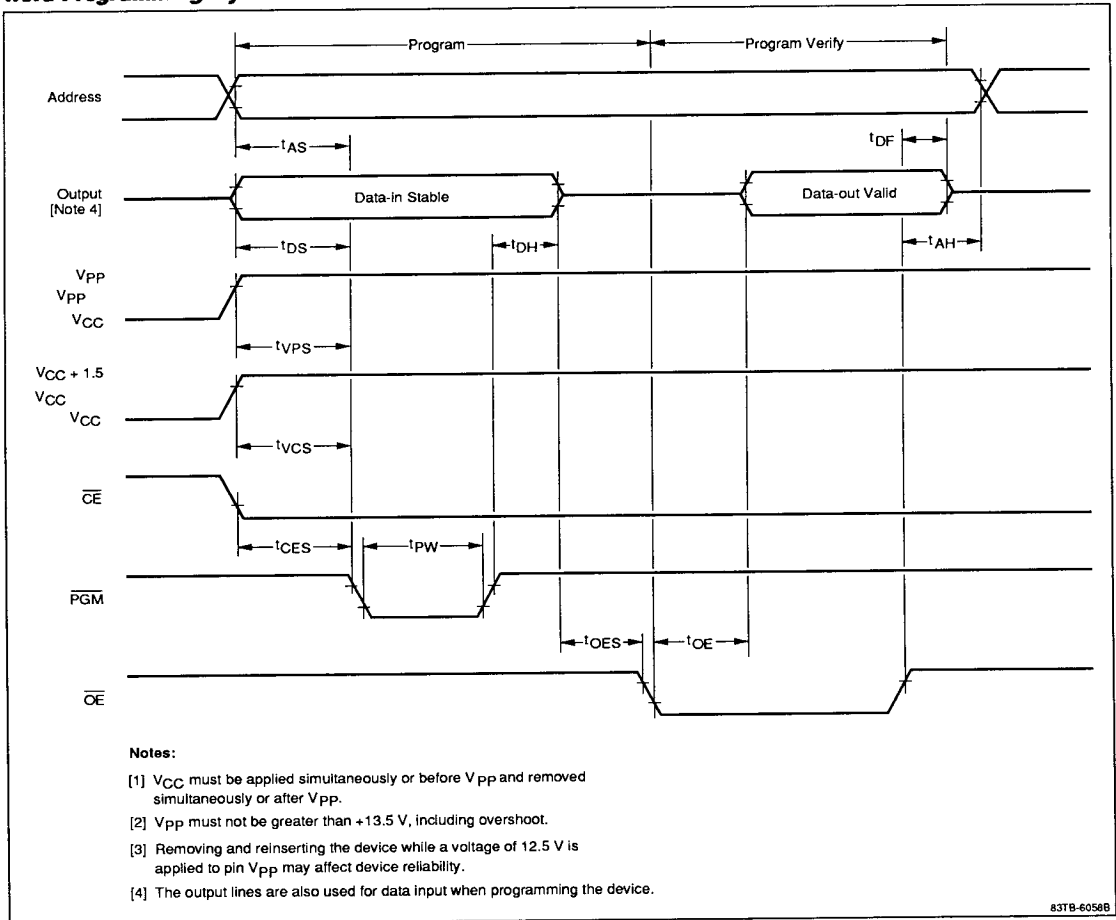


Figure 3 Word Programming Flowchart

